



## DESCRIPTION

AMCOM's AM244236WM-BM/FM-R is part of the GaAs MMIC power amplifier series. It has 31dB gain and 36dBm output power over the 2.4 to 4.2GHz band. This MMIC is in a ceramic package with both RF and DC leads at the lower level of the package to facilitate low-cost SMT assembly to the PC board. When mounting directly to PCB, please see application note AN700 for instructions. Because of high DC power dissipation, we strongly recommend to mount these devices directly on a metal heat sink. The AM244236WM-FM-R is the AM244236WM-BM-R mounted on a gold plated copper flange carrier. There are two screw holes on the flange to facilitate screwing on to a metal heat sink. This MMIC is RoHS compliant.

## FEATURES

- Wide bandwidth from 2.4 to 4.2GHz
- High output power,  $P_{1dB} = 36dBm$
- High gain, 31dB
- Fully matched; 50-ohm input/output impedance

## APPLICATIONS

- Wireless Internet Access
- Wireless Local Loop
- Two way radio

## PERFORMANCE\* ( $V_{ds} = 8V$ , $I_{dq} = 1500mA$ , $V_{gs}^{**} = -0.76V$ , $T_a = 25^{\circ}C$ )

Parameters	Minimum	Typical	Maximum
Frequency	2.6 – 4.0GHz	2.4 – 4.2GHz	
Gain (Small signal)	27dB	31dB	
Gain Ripple		$\pm 2.0dB$	$\pm 3dB$
$P_{1dB}$	35.0dBm	36.0dBm	
$P_{sat}$		36.5dBm	
Efficiency	20%	30%	
Input Return Loss	8dB	15dB	
Output Return Loss	8dB	12dB	
Thermal Resistance		6.1°C/W	

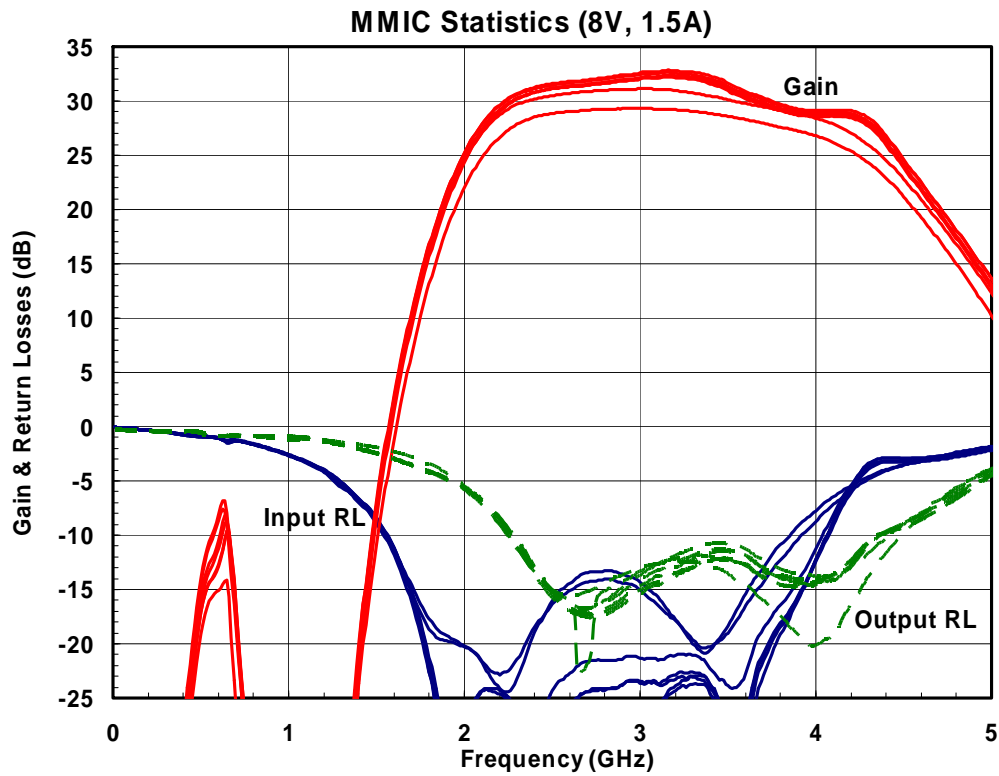
\* Specifications subject to change without notice

\*\* Gate voltage is for reference only and may vary from lot to lot

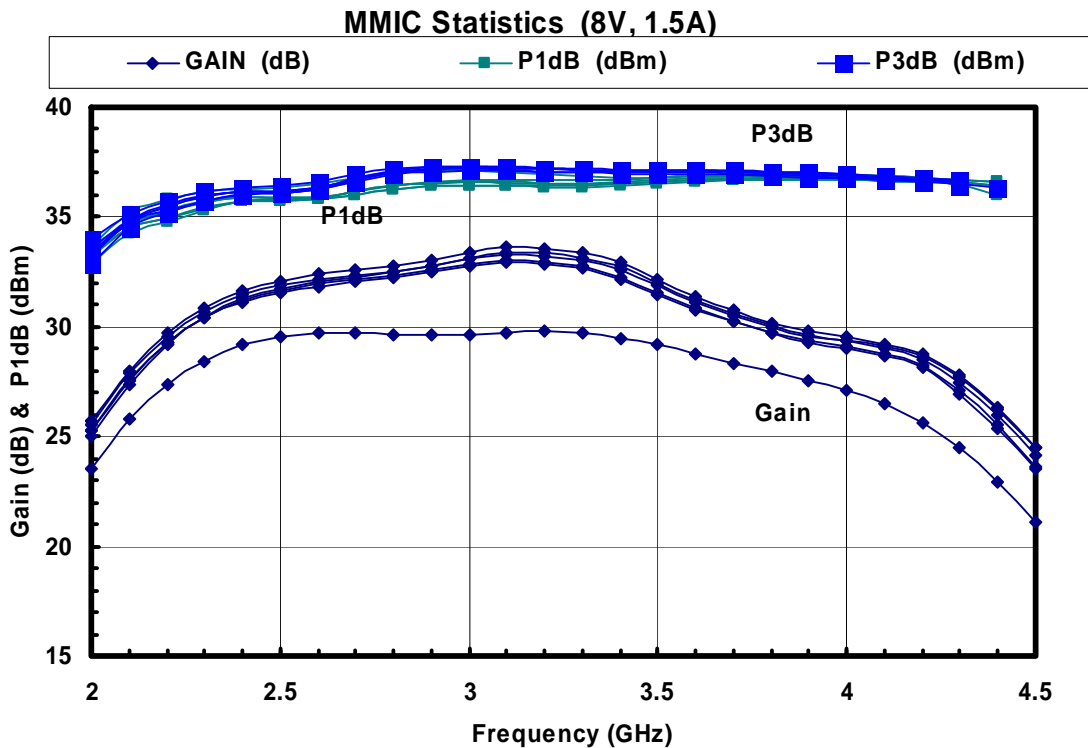
## ABSOLUTE MAXIMUM RATING

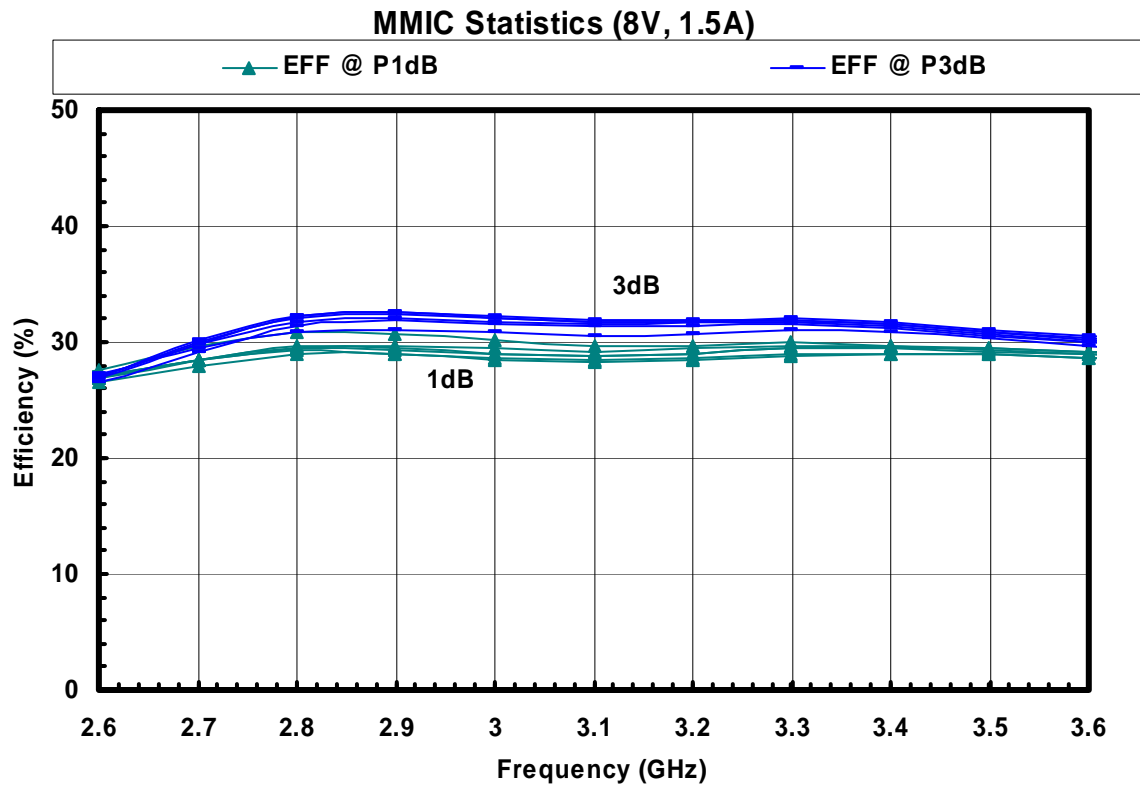
Parameters	Symbol	Rating
Drain source voltage	$V_{ds}$	10V
Gate source voltage	$V_{gs}$	-5V
Drain source current	$I_{ds}$	2.4A
Continuous dissipation at room temperature	$P_t$	24W
Channel temperature	$T_{ch}$	175°C
Operating temperature	$T_{op}$	-55°C to +100°C
Storage temperature	$T_{sto}$	-55°C to +135°C

SMALL SIGNAL DATA

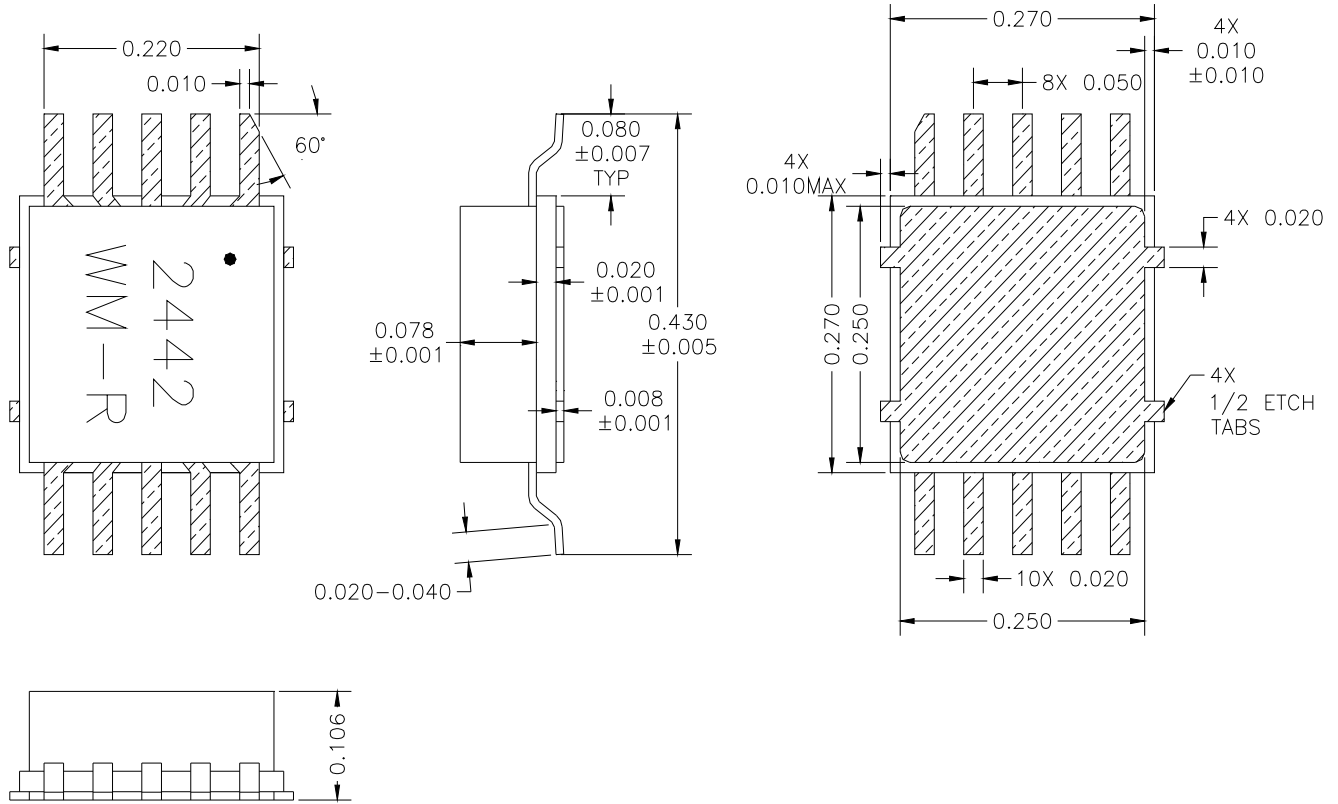


POWER DATA

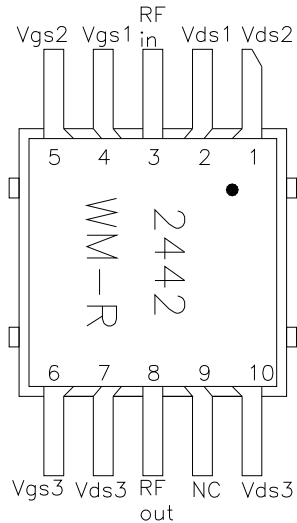




**PACKAGE OUTLINE (BM)**



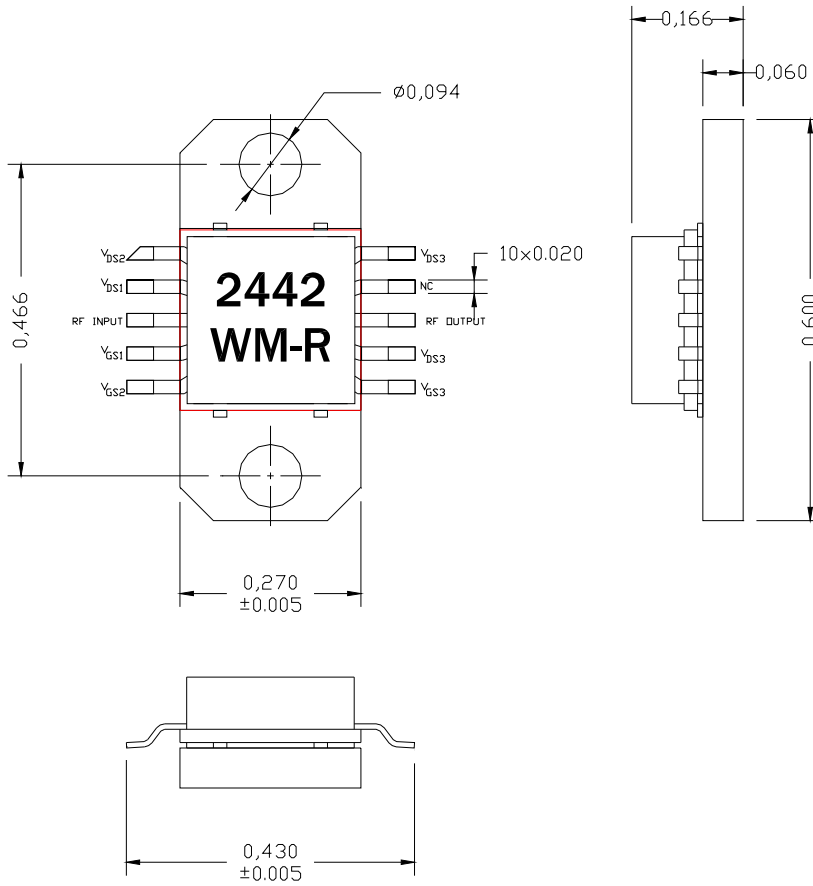
**PIN LAYOUT**



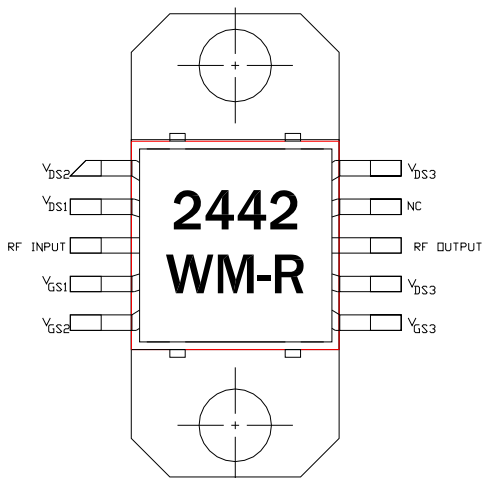
Pin No.	Function	Bias*
1	Vds2	+8V
2	Vds1	+8V
3	RF in	
4	Vgs1	-0.75V
5	Vgs2	-0.75V
6	Vgs3	-0.75V
7	Vds3	+8V
8	RF out	
9	NC	
10	Vds3	+8V

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PACKAGE OUTLINE (FM)



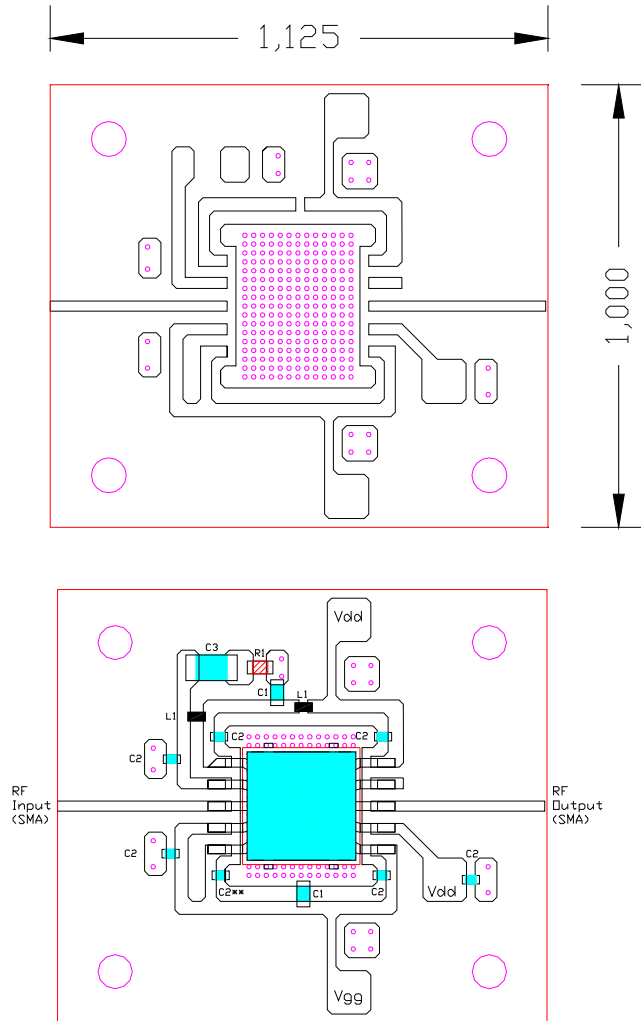
PIN LAYOUT



Pin No.	Function	Bias*
1	Vds2	+8V
2	Vds1	+8V
3	RF in	
4	Vgs1	-0.75V
5	Vgs2	-0.75V
6	Vgs3	-0.75V
7	Vds3	+8V
8	RF out	
9	NC	
10	Vds3	+8V

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TEST CIRCUIT OUTLINE (BM Package)



- Notes:
- 1- 10mils Rogers 4350 Material epoxied to D0007-0021A
  - 2- Ckt is for matched MMICs
  - 3- C1=0.56uF (0603), C2=1000pF (0402), C3=10uF (1206), R1=3 ohms (0603), L1=1nH (0402), \*\* May be omitted

Important Notes:

- 1- The MMIC should have a good heat sink to avoid overheating. If SMT is used use PC board thickness < 10 mils and ensure vias are filled with solder or metal to lower PCB heat resistance. MMIC could be attached on direct ground for lowest junction temperature.
- 2- Recommended current biases are 125mA, 275mA & 1100mA for the first, second and third stages respectively.
- 3- Do not apply  $V_{ds1}$ ,  $V_{ds2}$  &  $V_{ds3}$  without proper negative voltages on  $V_{gs1}$ ,  $V_{gs2}$  &  $V_{gs3}$ .
- 4- The currents flowing out of the  $V_{gs1}$ ,  $V_{gs2}$  &  $V_{gs3}$  pins are less than 100µA, 500µA & 10mA at  $P_{1dB}$ .
- 5- External 1 µF dipped tantalum capacitor should be attached to Vd and Vg to decouple external bias leads.